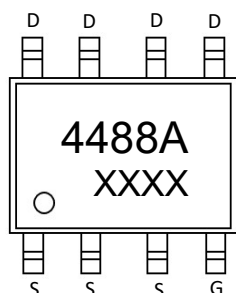


Features

- SGT MOSFET technology
- Low $R_{DS(on)}$ & FOM
- Extremely low switching loss
- Excellent stability and uniformity
- Fast switching and soft recovery

Application

- Power switching application

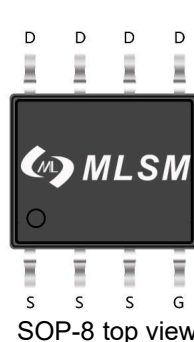


Marking and pin assignment

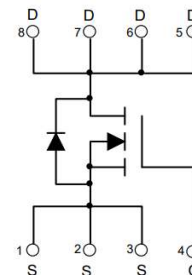
4488A: Device code
XXXX: Code

Product Summary

V_{DS}	$R_{DS(on)}$ MAX	I_D MAX
150V	65mΩ@10V	5A



SOP-8 top view



Schematic diagram



Halogen-Free

Absolute Maximum Ratings (TA=25°C unless otherwise noted)

Symbol	Parameter	Rating	Unit
--------	-----------	--------	------

Common Ratings (TC=25°C Unless Otherwise Noted)

V_{DS}	Drain-Source Breakdown Voltage	150	V
V_{GS}	Gate-Source Voltage	±20	V
T_J	Maximum Junction Temperature	150	°C
T_{STG}	Storage Temperature Range	-50 to 155	°C
I_S	Diode Continuous Forward Current	$T_c=25^\circ\text{C}$	5
			A

Mounted on Large Heat Sink

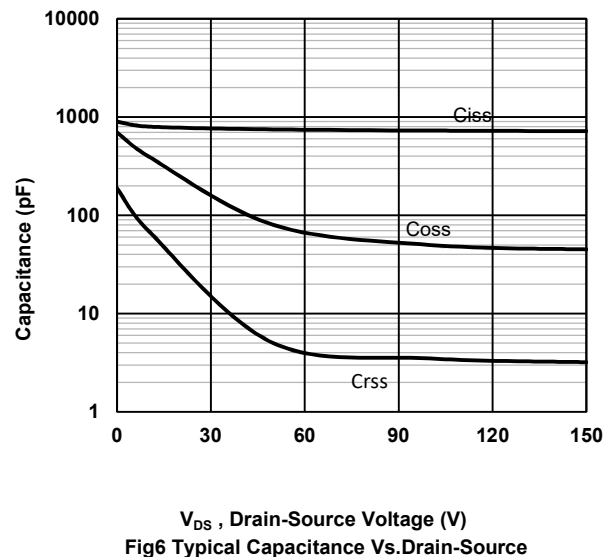
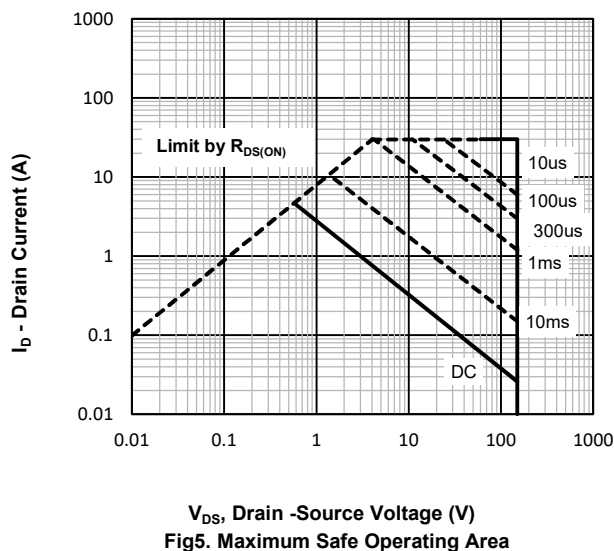
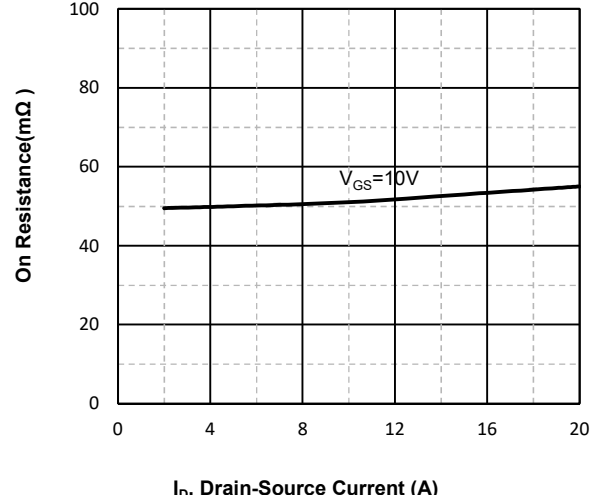
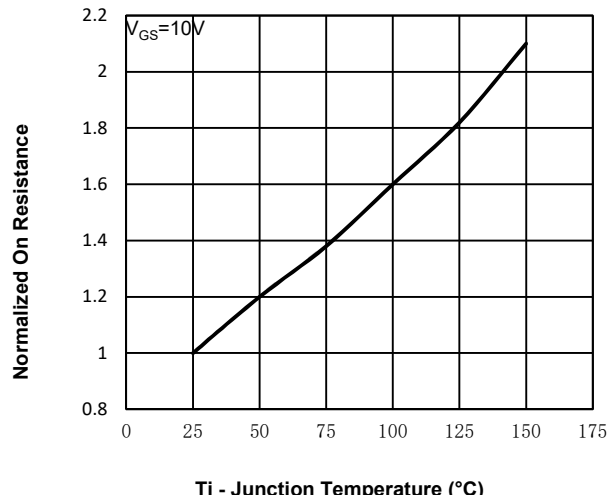
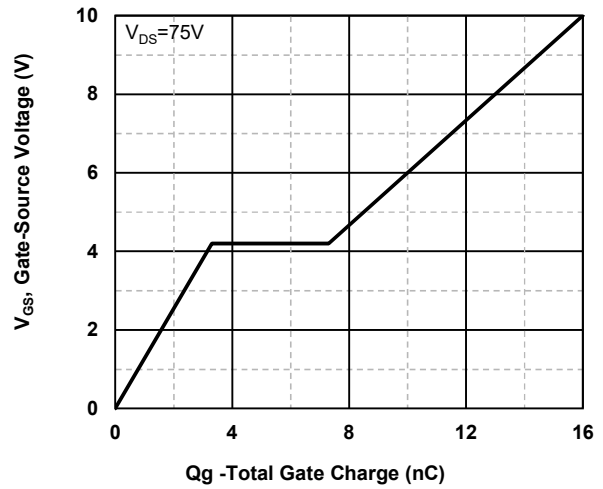
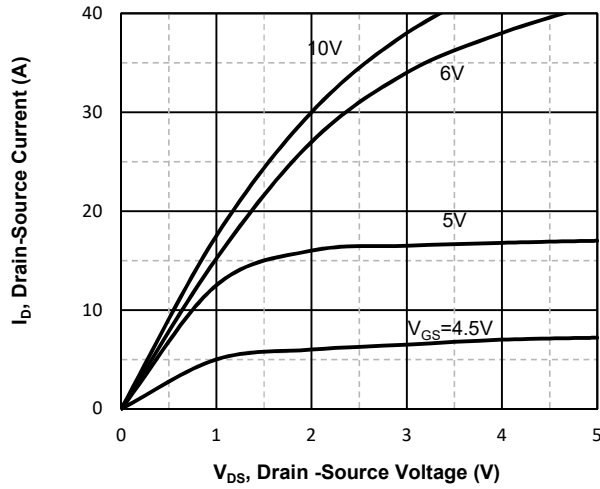
I_{DM}	Pulse Drain Current Tested	$T_c=25^\circ\text{C}$	30	A
I_D	Continuous Drain Current	$T_c=25^\circ\text{C}$	5	A
P_D	Maximum Power Dissipation	$T_c=25^\circ\text{C}$	2.6	W
$R_{\theta JA}$	Thermal Resistance Junction-Ambient		40	°C/W

Ordering Information (Example)

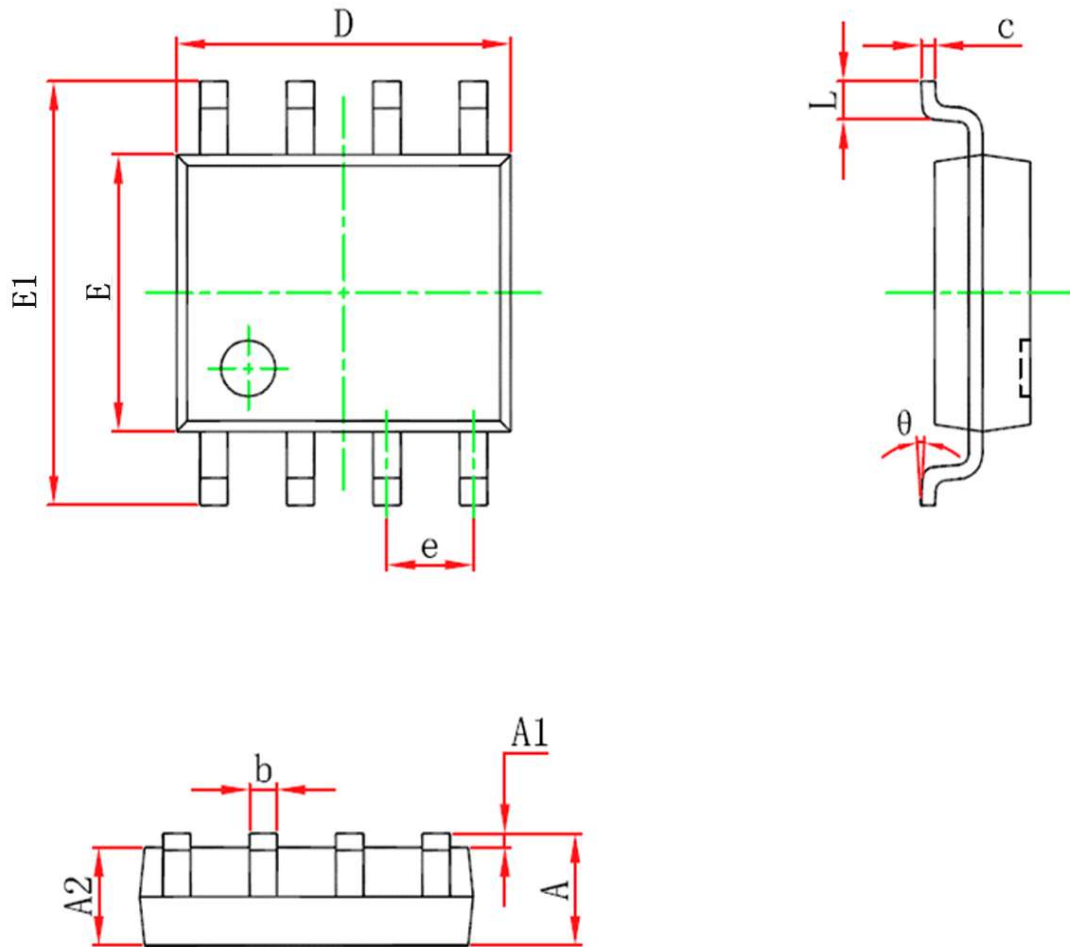
Type	Package	Marking	Minimum Package(pcs)	Inner Box Quantity(pcs)	Outer Carton Quantity(pcs)	Delivery Mode
MLSQ4488A	SOP-8	4488A	3,000	6,000	42,000	13"reel

Electrical Characteristics (TJ=25°C unless otherwise noted)						
Symbol	Parameter	Condition	Min	Typ	Max	Unit
Static Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
BV(BR)DSS	Drain-Source Breakdown Voltage	VGS=0V, ID=250μA	150	--	--	V
IDSS	Zero Gate Voltage Drain Current	VDS=150V, VGS=0V	--	--	1	μA
IGSS	Gate-Body Leakage Current	VGS=±20V, VDS=0V	--	--	±100	nA
VGS(th)	Gate Threshold Voltage	VDS=VGS, ID=250μA	2	3	4	V
RDS(on)	Drain-Source On-State Resistance	VGS=10V, ID=5A	--	50	65	mΩ
Dynamic Electrical Characteristics @ TJ = 25°C (unless otherwise stated)						
Ciss	Input Capacitance	VDS=75V, VGS=0V, f=1MHz	--	750	--	pF
Coss	Output Capacitance		--	65	--	pF
CRSS	Reverse Transfer Capacitance		--	5	--	pF
Switching Characteristics						
Qg	Total Gate Charge	VDS=75V, ID=5A, VGS=10V	--	16	--	nC
Qgs	Gate Source Charge		--	3	--	nC
Qgd	Gate Drain Charge		--	4	--	nC
td(on)	Turn-on Delay Time	VDD=75V, ID=5A, VGS=10V, RG=2.2Ω	--	7	--	nS
tr	Turn-on Rise Time		--	20	--	nS
td(off)	Turn-Off Delay Time		--	16	--	nS
tf	Turn-Off Fall Time		--	14	--	nS
Source- Drain Diode Characteristics						
VSD	Forward on voltage	TJ=25°C, IS=5A	--	0.9	1.2	V

Typical Operating Characteristics



SOP-8 Package information



Symbol	Dimensions in Millimeters(mm)		Dimensions In Inches	
	Min	Max	Min	Max
A	1.450	1.750	0.057	0.068
A1	0.100	0.250	0.003	0.009
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.012	0.020
c	0.170	0.250	0.006	0.009
D	4.700	5.100	0.185	0.200
e	1.270(BSC)		0.050(BSC)	
E	3.800	4.000	0.149	0.157
E1	5.800	6.200	0.228	0.244
L	0.400	1.270	0.015	0.050
θ	0°	8°	0°	8°